

TSM650P03CX

30V P-Channel Power MOSFET

SOT-23



Pin Definition:

1. Gate
2. Source
3. Drain

Key Parameter Performance

Parameter	Value	Unit
V_{DS}	-30	V
$R_{DS(on)}$ (max)	$V_{GS} = -10V$	65
	$V_{GS} = -4.5V$	75
	$V_{GS} = -2.5V$	100
Q_g	8	nC

Features

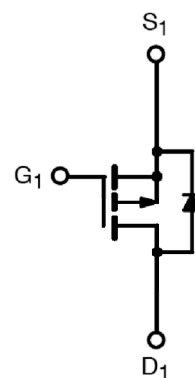
- Fast Switching
- Suited for -2.5V Gate Drive Applications
- Halogen-free

Ordering Information

Part No.	Package	Packing
TSM650P03CX RFG	SOT-23	3kcs / 7+Reel

Note: %G+denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



P-Channel MOSFET

Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	$T_C = 25^\circ C$	-4.1
		$T_C = 100^\circ C$	-2.6
Pulsed Drain Current ^(Note 1)	I_{DM}	-16.4	A
Power Dissipation @ $T_C = 25^\circ C$	P_D	1.56	W
Operating Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ C$

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	R_{JA}	80	$^\circ C/W$

Electrical Specifications ($T_C = 25^\circ\text{C}$ unless otherwise noted)

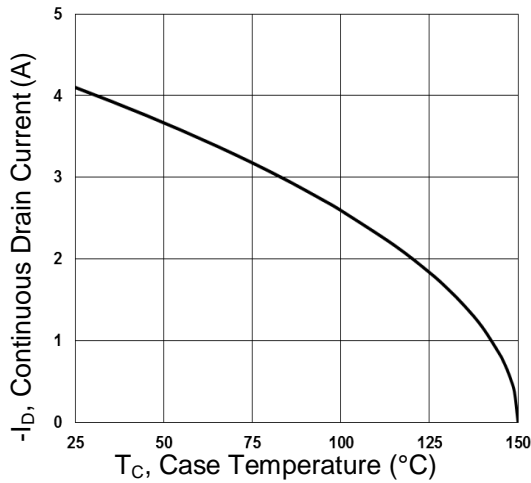
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$	BV_{DSS}	-30	--	--	V
Drain-Source On-State Resistance	$V_{GS} = -10\text{V}, I_D = -4\text{A}$	$R_{DS(on)}$	--	55	65	m
	$V_{GS} = -4.5\text{V}, I_D = -3\text{A}$		--	65	75	
	$V_{GS} = -2.5\text{V}, I_D = -2\text{A}$		--	85	100	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	$V_{GS(TH)}$	-0.4	-0.7	-0.9	V
Zero Gate Voltage Drain Current	$V_{DS} = -30\text{V}, V_{GS} = 0\text{V}$	I_{DSS}	--	--	-1	μA
	$V_{DS} = -24\text{V}, T_J = 125^\circ\text{C}$		--	--	-10	
Gate Body Leakage	$V_{GS} = \pm 12\text{V}, V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Forward Transconductance ^(Note 2)	$V_{DS} = -10\text{V}, I_D = -3\text{A}$	g_{fs}	--	5.4	--	S
Dynamic						
Total Gate Charge ^(Note 2,3)	$V_{DS} = -15\text{V}, I_D = -4\text{A},$ $V_{GS} = -4.5\text{V}$	Q_g	--	8	--	nC
Gate-Source Charge ^(Note 2,3)		Q_{gs}	--	1.9	--	
Gate-Drain Charge ^(Note 2,3)		Q_{gd}	--	1.4	--	
Input Capacitance	$V_{DS} = -15\text{V}, V_{GS} = 0\text{V},$ $f = 1.0\text{MHz}$	C_{iss}	--	810	--	μF
Output Capacitance		C_{oss}	--	85	--	
Reverse Transfer Capacitance		C_{rss}	--	50	--	
Switching						
Turn-On Delay Time ^(Note 2,3)	$V_{DD} = -15\text{V}, I_D = -1\text{A},$ $V_{GS} = -10\text{V}, R_{GEN} = 6$	$t_{d(on)}$	--	5.4	--	ns
Turn-On Rise Time ^(Note 2,3)		t_r	--	19.4	--	
Turn-Off Delay Time ^(Note 2,3)		$t_{d(off)}$	--	45.9	--	
Turn-Off Fall Time ^(Note 2,3)		t_f	--	12.4	--	
Source-Drain Diode Ratings and Characteristic						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	-4.1	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	-16.4	A
Diode-Source Forward Voltage	$V_{GS} = 0\text{V}, I_S = -1\text{A}$	V_{SD}	--	--	-1	V

Note:

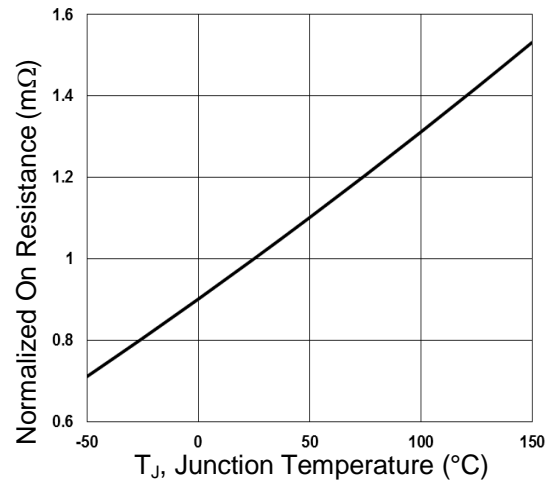
1. Pulse width limited by safe operating area
2. Pulse test: pulse width $m300\mu\text{s}$, duty cycle $m2\%$
3. Switching time is essentially independent of operating temperature.

Electrical Characteristics Curve

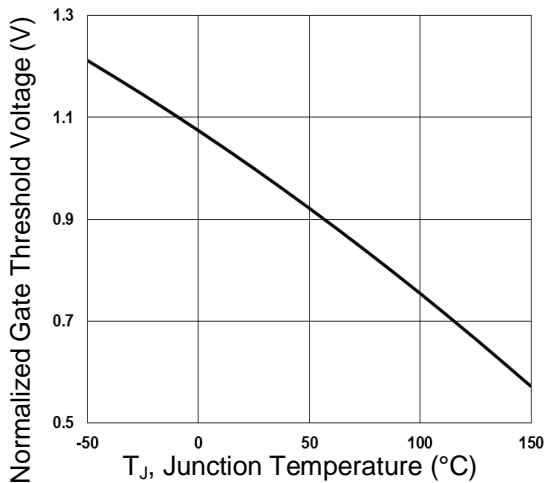
Continuous Drain Current vs. T_C



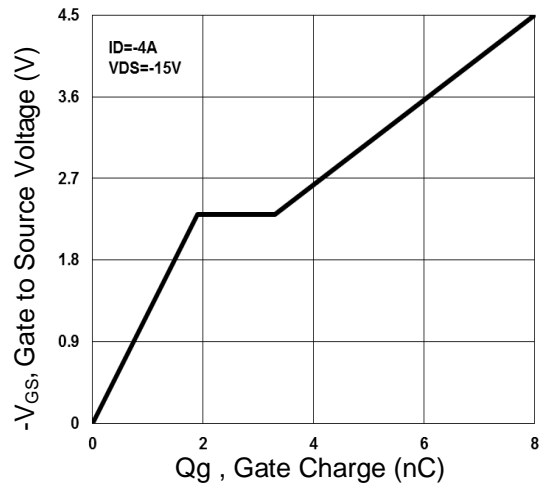
Normalized $R_{DS(on)}$ vs. T_J



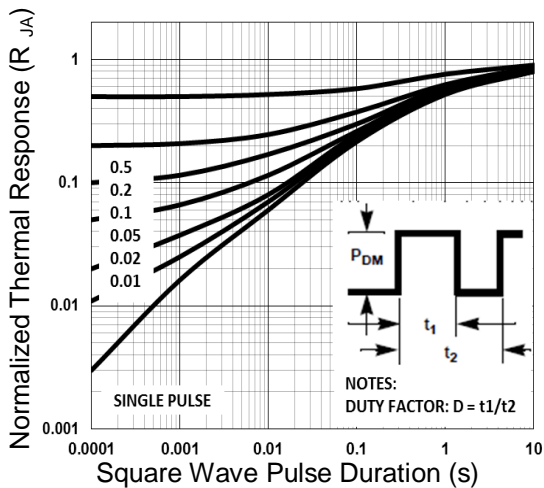
Threshold Voltage vs. Junction Temperature



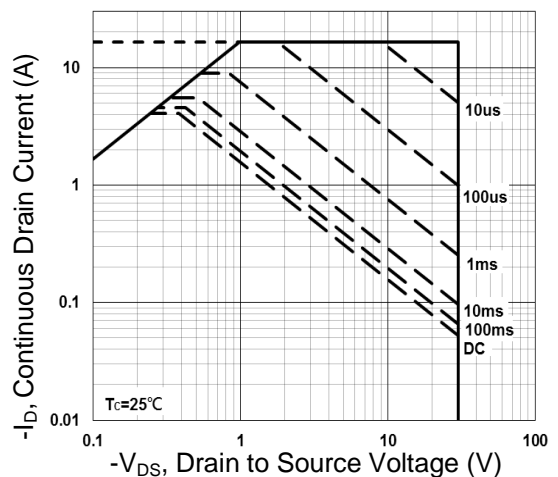
Gate Charge Waveform



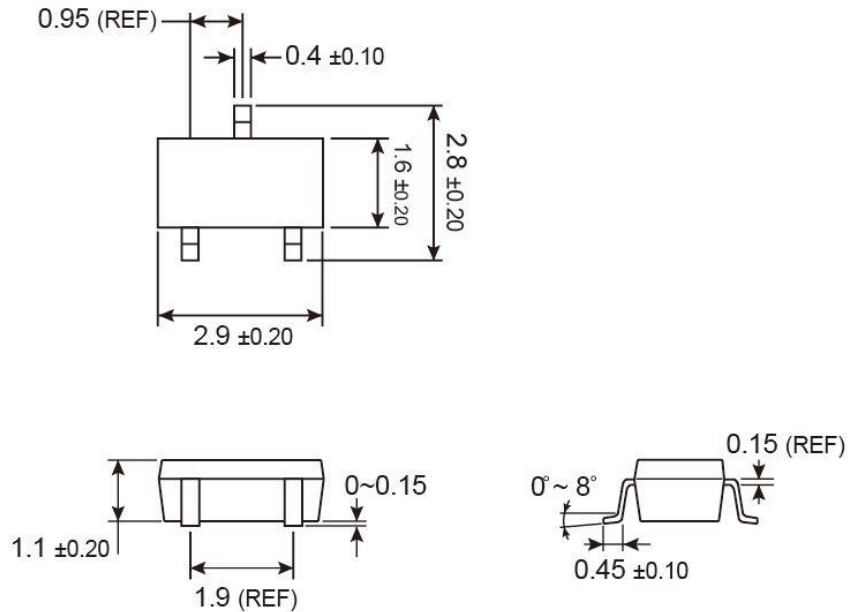
Normalized Thermal Transient Impedance Curve



Maximum Safe Operating Area

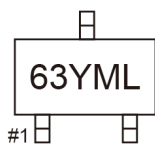


SOT-23 Mechanical Drawing



Unit: Millimeters

Marking Diagram



- 63** = Device Code
- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

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